DS4173-2.3

## **DS2107SY RECTIFIER DIODE**

**KEY PARAMETERS** 

 $V_{RRM}$ 4500V F(AV) 2590A

52500A

## **APPLICATIONS**

- Rectification.
- Freewheel Diode.
- DC Motor Control.
- Power Supplies.
- Welding.
- Battery Chargers.

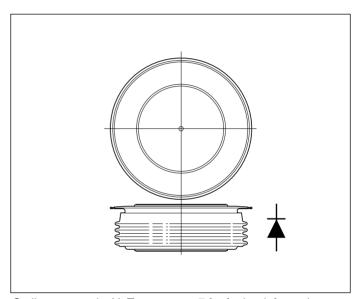
#### **FEATURES**

- Double Side Cooling.
- High Surge Capability.

#### **VOLTAGE RATINGS**

Type Number	Repetitive Peak Reverse Voltage V	Conditions
DS2107SY45	4500	$V_{RSM} = V_{RRM} + 100V$
DS2107SY44	4400	KOW KKW
DS2107SY43	4300	
DS2107SY42	4200	
DS2107SY41	4100	
DS2107SY40	4000	

Lower voltage grades available.



Outline type code: Y. Turn to page 7 for further information.

#### **CURRENT RATINGS**

Symbol	Parameter	Conditions	Max.	Units			
Double Side Cooled							
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load, T <sub>case</sub> = 100°C	2590	Α			
I <sub>F(RMS)</sub>	RMS value	T <sub>case</sub> = 100°C	4070	А			
I <sub>F</sub>	Continuous (direct) forward current	T <sub>case</sub> = 100°C	3510	А			
Single Side Cooled (Anode side)							
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load, T <sub>case</sub> = 100°C		А			
I <sub>F(RMS)</sub>	RMS value	$T_{case} = 100^{\circ}C$	2685	А			
I <sub>F</sub>	Continuous (direct) forward current	T <sub>case</sub> = 100°C	2110	Α			

## **DS2107SY**

## **SURGE RATINGS**

Symbol	Parameter	Conditions	Max.	Units
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10ms half sine; T <sub>case</sub> = 150°C	42.0	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	V <sub>R</sub> = 50% V <sub>RRM</sub> - 1/4 sine	8.82 x 10 <sup>6</sup>	A²s
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10ms half sine; T <sub>case</sub> = 150°C	52.5	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	V <sub>R</sub> = 0	13.8 x 10 <sup>6</sup>	A <sup>2</sup> s

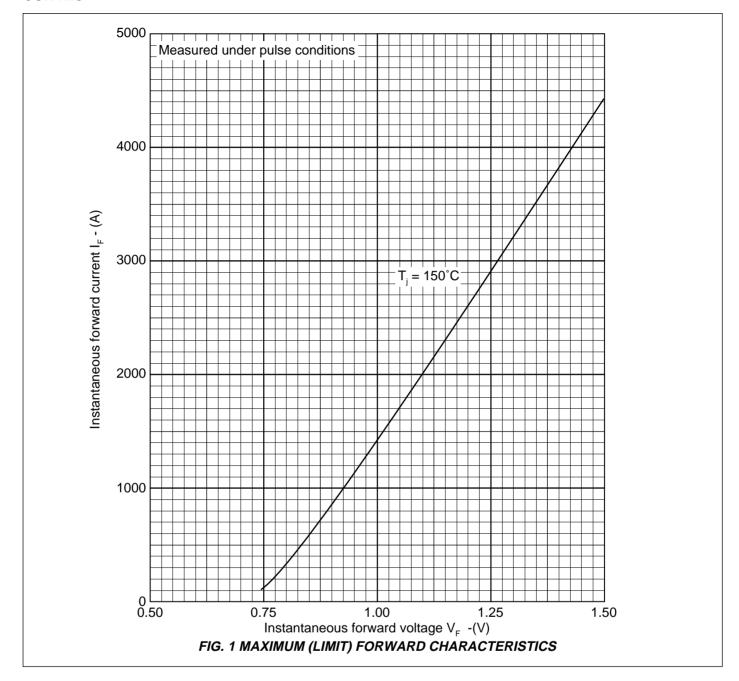
## THERMAL AND MECHANICAL DATA

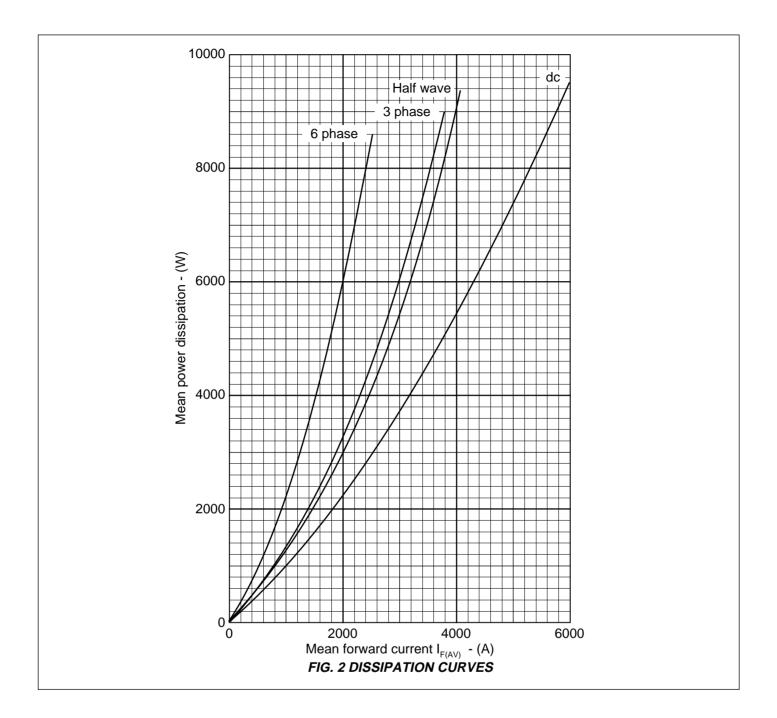
Symbol	Parameter	Conditions		Min.	Max.	Units
R <sub>th(j-c)</sub>	Thermal resistance - junction to case	Double side cooled	dc	-	0.0095	°C/W
		Single side cooled	Anode dc	-	0.019	°C/W
			Cathode dc	-	0.019	°C/W
R <sub>th(c-h)</sub>	Thermal resistance - case to heatsink	Clamping force 43.0kN with mounting compound	Double side	-	0.002	°C/W
			Single side	-	0.004	°C/W
T <sub>vj</sub>	Virtual junction temperature	Forward (conducting)	•	-	160	°C
		Reverse (blocking)		-	150	°C
T <sub>stg</sub>	Storage temperature range			-55	150	°C
-	Clamping force			38.0	47.0	kN

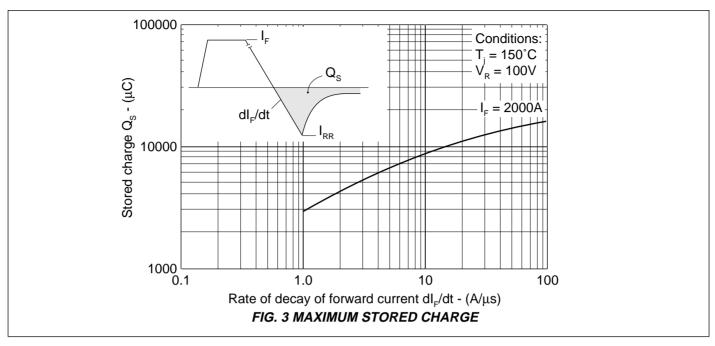
## **CHARACTERISTICS**

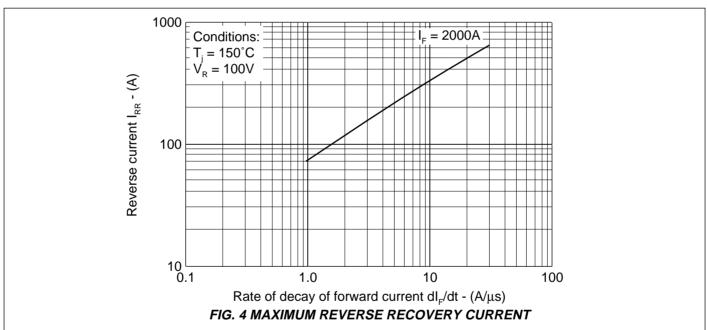
Symbol	Parameter	Conditions	Min.	Max.	Units
V <sub>FM</sub>	Forward voltage	At 3000A peak, T <sub>case</sub> = 25°C	-	1.275	V
I <sub>RRM</sub>	Peak reverse current	At V <sub>RRM</sub> , T <sub>case</sub> = 150°C	-	250	mA
Q <sub>s</sub>	Total stored charge	$I_F = 2000A$ , $dI_{RR}/dt = 3A/\mu s$	-	5000	μС
I <sub>RR</sub>	Peak recovery current	$T_{case} = 150^{\circ}C, V_{R} = 100V$	-	150	А
V <sub>TO</sub>	Threshold voltage	At T <sub>vj</sub> = 150°C	-	0.77	V
r <sub>T</sub>	Slope resistance	At T <sub>vj</sub> = 150°C	-	0.167	mΩ

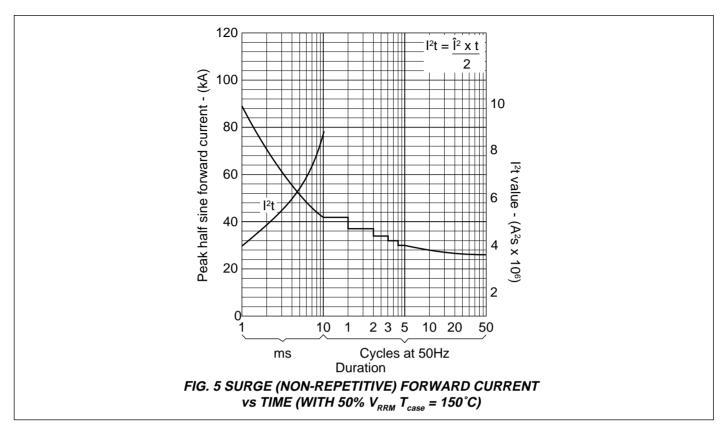
## **CURVES**

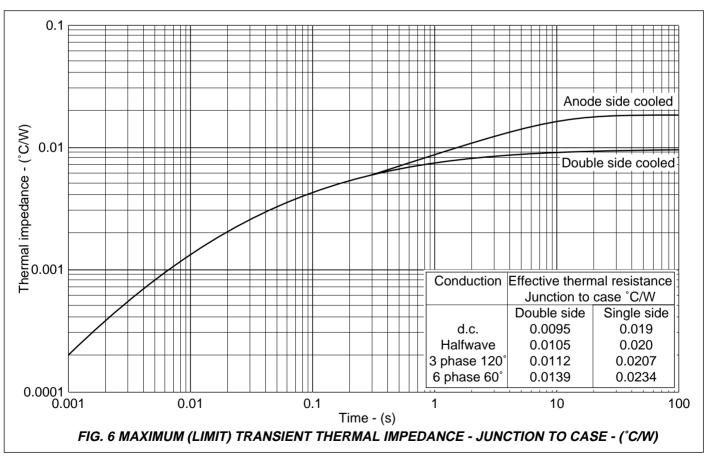






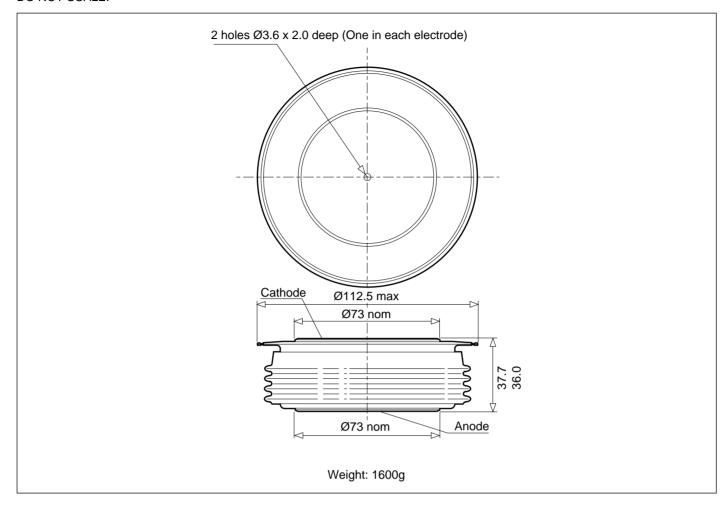






## **PACKAGE DETAILS - Y**

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.





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